TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

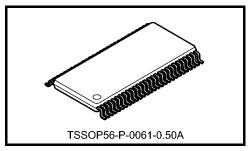
# **TC74VCX16841FT**

### Low-Voltage 20-Bit D-Type Latch with 3.6-V Tolerant Inputs and Outputs

The TC74VCX16841FT is a high-performance CMOS 20-bit D-type latch. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is also designed with overvoltage tolerant inputs and outputs up to  $3.6\ V.$ 

The TC74VCX16841FT can be used as two 10-bit latches or one 20-bit latch. The 20 latches are transparent D-type latches. The device has noninverting data (D) inputs and provides true data at its outputs. While the latch-enable (1LE or 2LE) input is high, the Q outputs of the corresponding 10-bit latch follow the D inputs. When LE is taken low, the Q outputs are latched at the



Weight: 0.25 g (typ.)

levels set up at the D inputs. When the OE input is high, the outputs are in a high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.

#### **Features**

- Low-voltage operation:  $V_{CC} = 1.8 \text{ to } 3.6 \text{ V}$
- High-speed operation:  $t_{pd} = 3.0 \text{ ns (max) (V}_{CC} = 3.0 \text{ to } 3.6 \text{ V})$

 $t_{pd} = 3.4 \text{ ns (max) (VCC} = 2.3 \text{ to } 2.7 \text{ V)}$ 

 $: t_{pd} = 6.8 \text{ ns (max) (V}_{CC} = 1.8 \text{ V})$ 

- Output current:  $I_{OH}/I_{OL} = \pm 24$  mA (min) ( $V_{CC} = 3.0$  V)
  - $: I_{OH}/I_{OL} = \pm 18 \text{ mA (min) (V}_{CC} = 2.3 \text{ V)}$
  - $: I_{OH}/I_{OL} = \pm 6 \text{ mA (min) (V}_{CC} = 1.8 \text{ V)}$
- Latch-up performance: -300 mA
- ESD performance: Machine model  $\geq \pm 200 \text{ V}$

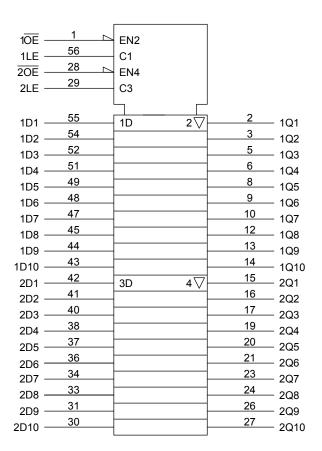
Human body model  $\geq \pm 2000 \text{ V}$ 

- Package: TSSOP
- 3.6-V tolerant function and power-down protection provided on all inputs and outputs

### Pin Assignment (top view)

#### 10E 56 1LE 1Q1 2 1D1 55 1Q2 3 1D2 54 GND 4 **GND** 53 1Q3 5 1D3 52 1Q4 6 51 1D4 7 $V_{CC}$ 50 $V_{CC}$ 1Q5 8 1D5 49 1Q6 9 48 1D6 1Q7 10 1D7 47 GND 11 46 **GND** 1Q8 12 1D8 45 1Q9 13 1D9 1Q10 14 43 1D10 2Q1 15 42 2D1 2D2 2Q2 16 41 2Q3 17 40 2D3 GND 18 39 **GND** 2D4 2Q4 19 38 2D5 2Q5 20 37 2Q6 21 36 2D6 $V_{\text{CC}}$ 22 35 Vcc 2Q7 23 34 2D7 2D8 2Q8 24 33 GND 25 **GND** 32 2Q9 26 2D9 31 2D10 2Q10 27 30 2<del>OE</del> 28 2LE 29

### **IEC Logic Symbol**



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### Truth Table (each 10-bit latch)

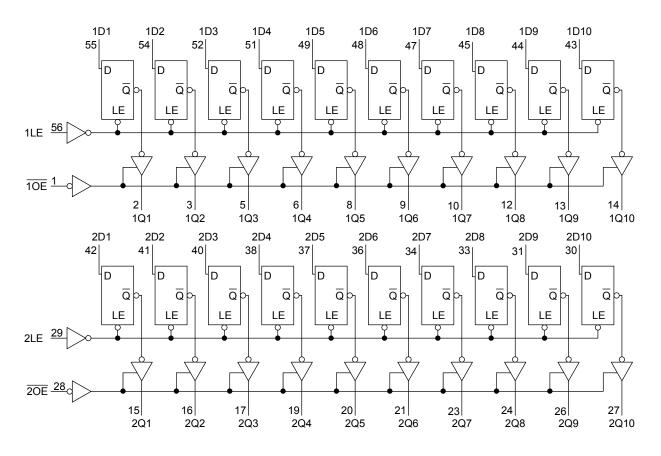
|    | Output |   |     |
|----|--------|---|-----|
| ŌĒ | LE     | D | · Q |
| L  | Н      | Н | Н   |
| L  | Н      | L | L   |
| L  | L      | Х | Qn  |
| Н  | Х      | Х | Z   |

X: Don't care

Z: High impedance

Qn: Q outputs are latched at the time when the LE input is taken to a low logic level.

### **System Diagram**



#### **Absolute Maximum Ratings (Note 1)**

| Characteristics                                   | Symbol                            | Rating                        | Unit |
|---|-----------------------------------|-------------------------------|------|
| Power supply voltage                              | V <sub>CC</sub>                   | -0.5 to 4.6                   | V    |
| DC input voltage                                  | V <sub>IN</sub>                   | -0.5 to 4.6                   | V    |
|   |                                   | -0.5 to 4.6 (Note 2)          |      |
| DC output voltage                                 | $V_{OUT}$                         | –0.5 to V <sub>CC</sub> + 0.5 | V    |
|   |                                   | (Note 3)                      |      |
| Input diode current                               | $I_{IK}$                          | -50                           | mA   |
| Output diode current                              | I <sub>OK</sub>                   | ±50 (Note 4)                  | mA   |
| DC output current                                 | lout                              | ±50                           | mA   |
| Power dissipation                                 | $P_{D}$                           | 400                           | mW   |
| DC V <sub>CC</sub> /ground current per supply pin | I <sub>CC</sub> /I <sub>GND</sub> | ±100                          | mA   |
| Storage temperature                               | T <sub>stg</sub>                  | -65 to 150                    | °C   |

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: OFF state

Note 3: High or low state.  $I_{\mbox{\scriptsize OUT}}$  absolute maximum rating must be observed.

Note 4:  $V_{OUT} < GND, V_{OUT} > V_{CC}$ 

#### **Operating Ranges (Note 1)**

| Characteristics          | Symbol                           | Rating                        | Unit |  |
|--------------------------|----------------------------------|-------------------------------|------|--|
| Power supply voltage     | V <sub>CC</sub>                  | 1.8 to 3.6                    | V    |  |
| Tower supply voltage     | VCC                              | 1.2 to 3.6 (Note 2)           | V    |  |
| Input voltage            | V <sub>IN</sub>                  | -0.3 to 3.6                   | V    |  |
| Output voltage           | Vour                             | 0 to 3.6 (Note 3)             | V    |  |
| Output voltage           | V <sub>OUT</sub>                 | 0 to V <sub>CC</sub> (Note 4) |      |  |
|                          |                                  | ±24 (Note 5)                  |      |  |
| Output current           | I <sub>OH</sub> /I <sub>OL</sub> | ±18 (Note 6)                  | mA   |  |
|                          |                                  | ±6 (Note 7)                   |      |  |
| Operating temperature    | T <sub>opr</sub>                 | -40 to 85                     | °C   |  |
| Input rise and fall time | dt/dv                            | 0 to 10 (Note 8)              | ns/V |  |

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3: OFF state

Note 4: High or low state

Note 5:  $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$ 

Note 6:  $V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$ 

Note 7:  $V_{CC} = 1.8 \text{ V}$ 

Note 8:  $V_{IN} = 0.8$  to 2.0 V,  $V_{CC} = 3.0$  V



### **Electrical Characteristics**

### DC Characteristics (Ta = -40 to 85°C, 2.7 V < $V_{\text{CC}} \leq 3.6 \text{ V})$

| Characteri                      | stics           | Symbol                        | Test Condition  |                           | N/ 00               | Min                   | Max                                   | Unit |
|---------------------------------|-----------------|-------------------------------|---|---------------------------|---------------------|-----------------------|---------------------------------------|------|
|                                 | H-level         | V <sub>IH</sub>               |   |                           | V <sub>CC</sub> (V) | 2.0                   |                                       |      |
| Input voltage                   | L-level         | VIL                           |   |                           | 2.7 to 3.6          |                       | 0.8                                   | V    |
|                                 | L-level         | VIL                           |   | I <sub>OH</sub> = -100 μA | 2.7 to 3.6          | V <sub>CC</sub> – 0.2 | — — — — — — — — — — — — — — — — — — — |      |
|                                 | H-level         | V <sub>OH</sub>               | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>II</sub>                            | I <sub>OH</sub> = -12 mA  | 2.7                 | 2.2                   | _                                     |      |
|                                 |                 |                               |   | I <sub>OH</sub> = -18 mA  | 3.0                 | 2.4                   | _                                     |      |
| Output voltage                  |                 |                               |   | I <sub>OH</sub> = -24 mA  | 3.0                 | 2.2                   | _                                     | V    |
| , ,                             | <u> </u>        |                               |   | I <sub>OL</sub> = 100 μA  | 2.7 to 3.6          | _                     | 0.2                                   |      |
| L-level                         | V <sub>OL</sub> | $V_{IN} = V_{IH}$ or $V_{IL}$ | I <sub>OL</sub> = 12 mA   | 2.7                       | _                   | 0.4                   |                                       |      |
|                                 |                 |                               | I <sub>OL</sub> = 18 mA   | 3.0                       | _                   | 0.4                   |                                       |      |
|                                 |                 |                               |   | I <sub>OL</sub> = 24 mA   | 3.0                 | _                     | 0.55                                  |      |
| Input leakage curre             | nt              | I <sub>IN</sub>               | V <sub>IN</sub> = 0 to 3.6 V  | ·                         | 2.7 to 3.6          | _                     | ±5.0                                  | μА   |
| 3-state output OFF              | state current   | I <sub>OZ</sub>               | $V_{IN} = V_{IH} \text{ or } V_{IL}$<br>$V_{OUT} = 0 \text{ to } 3.6 \text{ V}$ |                           | 2.7 to 3.6          | _                     | ±10.0                                 | μА   |
| Power-off leakage               | current         | loff                          | V <sub>IN</sub> , V <sub>OUT</sub> = 0 to 3.6 V                                 |                           | 0                   | _                     | 10.0                                  | μА   |
|                                 |                 |                               | V <sub>IN</sub> = V <sub>CC</sub> or GND  |                           | 2.7 to 3.6          | _                     | 20.0                                  |      |
| Quiescent supply c              | urrem           | Icc                           | $V_{CC} \le (V_{IN}, V_{OUT}) \le$  | 3.6 V                     | 2.7 to 3.6          | _                     | ±20.0                                 | μΑ   |
| Increase in I <sub>CC</sub> per | input           | Δlcc                          | $V_{IH} = V_{CC} - 0.6 V$   |                           | 2.7 to 3.6          | _                     | 750                                   |      |

### DC Characteristics (Ta = -40 to 85°C, 2.3 V $\leq$ V<sub>CC</sub> $\leq$ 2.7 V)

| Character                        | ristics       | Symbol          | Test Condition  |                                 | V <sub>CC</sub> (V)             | Min                      | Max   | Unit |     |  |
|----------------------------------|---------------|-----------------|---|---------------------------------|---------------------------------|--------------------------|-------|------|-----|--|
| lanut valtana                    | H-level       | V <sub>IH</sub> |   | _                               | 2.3 to 2.7                      | 1.6                      | _     | V    |     |  |
| Input voltage                    | L-level       | V <sub>IL</sub> |   | _                               | 2.3 to 2.7                      |                          | 0.7   | V    |     |  |
|                                  |               |                 |   | Ι <sub>ΟΗ</sub> = -100 μΑ       | 2.3 to 2.7                      | V <sub>CC</sub><br>- 0.2 | _     |      |     |  |
|                                  | H-level       | Voh             | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>            | $I_{OH} = -6 \text{ mA}$        | 2.3                             | 2.0                      | _     |      |     |  |
|                                  |               |                 |   | I <sub>OH</sub> = -12 mA        | 2.3                             | 1.8                      | _     | V    |     |  |
| Output voltage                   | tput voltage  |                 |   | I <sub>OH</sub> = -18 mA        | 2.3                             | 1.7                      | _     |      |     |  |
|                                  |               |                 | $V_{IN} = V_{IH}$ or $V_{IL}$                                   | $I_{OL} = 100 \mu A$            | 2.3 to 2.7                      | _                        | 0.2   |      |     |  |
|                                  | L-level       | V <sub>OL</sub> |   | $V_{IN} = V_{IH} \ or \ V_{IL}$ | $V_{IN} = V_{IH} \ or \ V_{IL}$ | I <sub>OL</sub> = 12 mA  | 2.3   | _    | 0.4 |  |
|                                  |               |                 |   | I <sub>OL</sub> = 18 mA         | 2.3                             | _                        | 0.6   |      |     |  |
| Input leakage curre              | ent           | I <sub>IN</sub> | V <sub>IN</sub> = 0 to 3.6 V                                    | ·                               | 2.3 to 2.7                      | _                        | ±5.0  | μА   |     |  |
| 3 state output OEE               | etato current | loz             | $V_{IN} = V_{IH}$ or $V_{IL}$                                   | $V_{IN} = V_{IH}$ or $V_{IL}$   |                                 |                          | ±10.0 | ^    |     |  |
| 3-state output OFF state current |               | loz             | V <sub>OUT</sub> = 0 to 3.6 V                                   |                                 | 2.3 to 2.7                      |                          | ±10.0 | μА   |     |  |
| Power-off leakage                | current       | loff            | V <sub>IN</sub> , V <sub>OUT</sub> = 0 to 3.6 V                 |                                 | 0                               |                          | 10.0  | μΑ   |     |  |
| Quiescent supply of              | current       |                 | $V_{IN} = V_{CC}$ or GND  |                                 | 2.3 to 2.7                      |                          | 20.0  | Δ    |     |  |
| Quiescerit supply t              | Julieni       | Icc             | V <sub>CC</sub> ≤ (V <sub>IN</sub> , V <sub>OUT</sub> ) ≤ 3.6 V |                                 | 2.3 to 2.7                      | _                        | ±20.0 | μА   |     |  |



### DC Characteristics (Ta = -40 to 85°C, 1.8 V $\leq$ V<sub>CC</sub> < 2.3 V)

| Characteristics Sy   |               | Symbol           | Test Condition  |                           |            | Min   | Max                      | Unit |
|----------------------|---------------|------------------|---|---------------------------|------------|---|--------------------------|------|
|                      |               | Í                |   | root condition            |            |   |                          |      |
| Input voltage        | H-level       | V <sub>IH</sub>  | _   | _                         | 1.8 to 2.3 | $\begin{array}{c} 0.7 \times \\ V_{CC} \end{array}$ | _                        | V    |
| input voitage        | L-level       | V <sub>IL</sub>  | _   | _                         | 1.8 to 2.3 |   | 0.2 ×<br>V <sub>CC</sub> | V    |
|                      | H-level       | V <sub>OH</sub>  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>                            | I <sub>OH</sub> = -100 μA | 1.8        | V <sub>CC</sub><br>- 0.2                            | _                        | V    |
| Output voltage       |               |                  |   | $I_{OH} = -6 \text{ mA}$  | 1.8        | 1.4   | _                        |      |
|                      | L-level       | .,               | V <sub>OL</sub> V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>            | I <sub>OL</sub> = 100 μA  | 1.8        | _   | 0.2                      |      |
|                      | L-level       | V <sub>OL</sub>  | AIN — AIH OI AIL  | I <sub>OL</sub> = 6 mA    | 1.8        | _   | 0.3                      |      |
| Input leakage currer | nt            | I <sub>IN</sub>  | V <sub>IN</sub> = 0 to 3.6 V  |                           | 1.8        | _   | ±5.0                     | μА   |
| 3-state output OFF   | state current | I <sub>OZ</sub>  | $V_{IN} = V_{IH} \text{ or } V_{IL}$<br>$V_{OUT} = 0 \text{ to } 3.6 \text{ V}$ |                           | 1.8        | _   | ±10.0                    | μА   |
| Power-off leakage of | urrent        | I <sub>OFF</sub> | V <sub>IN</sub> , V <sub>OUT</sub> = 0 to 3.6 V                                 |                           | 0          | _   | 10.0                     | μА   |
| Quioscont supply of  | ırront        | loo              | V <sub>IN</sub> = V <sub>CC</sub> or GND  |                           | 1.8        |   | 20.0                     | ^    |
| Quiescent supply cu  | III CIII      | Icc              | $V_{CC} \le (V_{IN}, V_{OUT}) \le 3.6 \text{ V}$                                |                           | 1.8        | _   | ±20.0                    | μА   |

## AC Characteristics (Ta = –40 to 85°C, input: $t_r = t_f$ = 2.0 ns, $C_L$ = 30 pF, $R_L$ = 500 $\Omega$ ) (Note 1)

| Characteristics               | Symbol             | Symbol Test Condition |                     | Min Ma |       | Unit  |
|-------------------------------|--------------------|-----------------------|---------------------|--------|-------|-------|
| Cridiacteristics              | Symbol             | rest Condition        | V <sub>CC</sub> (V) | IVIIII | IVIAX | Offic |
| Propagation delay time        | <b></b>            |                       | 1.8                 | 1.5    | 6.8   |       |
| (D-Q)                         | t <sub>pLH</sub>   | Figure 1, Figure 2    | $2.5 \pm 0.2$       | 1.0    | 3.4   | ns    |
| (D-Q)                         | t <sub>pHL</sub>   |                       | $3.3 \pm 0.3$       | 0.8    | 3.0   |       |
| Drangation delay time         | 4                  |                       | 1.8                 | 1.5    | 8.8   |       |
| Propagation delay time (LE-Q) | t <sub>pLH</sub>   | Figure 1, Figure 2    | $2.5 \pm 0.2$       | 1.0    | 4.4   | ns    |
| (LE-Q)                        | t <sub>pHL</sub>   |                       | $3.3 \pm 0.3$       | 0.8    | 3.5   |       |
|                               |                    |                       | 1.8                 | 1.5    | 9.8   |       |
| 3-state output enable time    | t <sub>pZL</sub>   | Figure 1, Figure 3    | $2.5\pm0.2$         | 1.0    | 4.9   | ns    |
|                               | <sup>t</sup> pZH   |                       | $3.3 \pm 0.3$       | 0.8    | 3.8   |       |
|                               | 4                  | Figure 1, Figure 3    | 1.8                 | 1.5    | 7.6   | ns    |
| 3-state output disable time   | t <sub>pLZ</sub>   |                       | $2.5 \pm 0.2$       | 1.0    | 4.2   |       |
|                               | t <sub>pHZ</sub>   |                       | $3.3 \pm 0.3$       | 0.8    | 3.7   |       |
| NAimine une mule e vuidă      |                    | Figure 1, Figure 2    | 1.8                 | 4.0    | _     |       |
| Minimum pulse width           | t <sub>W (H)</sub> |                       | $2.5\pm0.2$         | 1.5    | _     | ns    |
| (LE)                          |                    |                       | $3.3 \pm 0.3$       | 1.5    | _     |       |
|                               |                    |                       | 1.8                 | 2.5    | _     |       |
| Minimum setup time            | ts                 | Figure 1, Figure 2    | $2.5 \pm 0.2$       | 1.5    | _     | ns    |
|                               |                    |                       | $3.3 \pm 0.3$       | 1.5    | _     |       |
|                               |                    |                       | 1.8                 | 1.0    | _     |       |
| Minimum hold time             | t <sub>h</sub>     | Figure 1, Figure 2    | $2.5 \pm 0.2$       | 1.0    | _     | ns    |
|                               |                    |                       | $3.3 \pm 0.3$       | 1.0    |       |       |
|                               |                    |                       | 1.8                 | _      | 0.5   |       |
| Output to output skew         | t <sub>osLH</sub>  | (Note 2)              | $2.5 \pm 0.2$       | _      | 0.5   | ns    |
|                               | t <sub>osHL</sub>  |                       | $3.3 \pm 0.3$       | _      | 0.5   |       |

Note 1: For  $C_L = 50 \ pF$ , add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|)$ 



### **Dynamic Switching Characteristics**

(Ta = 25°C, input:  $t_r = t_f = 2.0 \text{ ns}, C_L = 30 \text{ pF}, R_L = 500 \Omega$ )

| Characteristics                                 | Symbol           | Test Condition                                    |       |                     | Тур.  | Unit |
|---|------------------|---|-------|---------------------|-------|------|
|   | ,                |   |       | V <sub>CC</sub> (V) | ,.    |      |
|   |                  | $V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (N | lote) | 1.8                 | 0.25  |      |
| Quiet output maximum dynamic V <sub>OL</sub>    | V <sub>OLP</sub> | $V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (N | lote) | 2.5                 | 0.6   | V    |
|   |                  | $V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (N | lote) | 3.3                 | 8.0   |      |
|   | 02.              | $V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (N | lote) | 1.8                 | -0.25 | ٧    |
| Quiet output minimum dynamic V <sub>OI</sub>    |                  | $V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (N | lote) | 2.5                 | -0.6  |      |
|   |                  | $V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (N | lote) | 3.3                 | -0.8  |      |
|   |                  | $V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (N | lote) | 1.8                 | 1.5   |      |
| Quiet output minimum<br>dynamic V <sub>OH</sub> |                  | $V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (N | lote) | 2.5                 | 1.9   | V    |
|   |                  | $V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (N | lote) | 3.3                 | 2.2   |      |

Note: Parameter guaranteed by design.

### **Capacitive Characteristics (Ta = 25°C)**

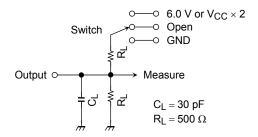
| Characteristics               | Symbol           | Test Condition            |        | V <sub>CC</sub> (V) | Тур. | Unit |
|-------------------------------|------------------|---------------------------|--------|---------------------|------|------|
| lanut conscitores             | -                |                           |        |                     | 0    |      |
| Input capacitance             | C <sub>IN</sub>  | <del>-</del>              |        | 1.8, 2.5, 3.3       | б    | pF   |
| Output capacitance            | C <sub>OUT</sub> | _                         |        | 1.8, 2.5, 3.3       | 7    | pF   |
| Power dissipation capacitance | C <sub>PD</sub>  | $f_{IN} = 10 \text{ MHz}$ | (Note) | 1.8, 2.5, 3.3       | 20   | pF   |

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/20 \text{ (per bit)}$ 

### **AC Test Circuit**



| Parameter                           | Switch  |  |  |  |
|-------------------------------------|---|--|--|--|
| t <sub>pLH</sub> , t <sub>pHL</sub> | Open  |  |  |  |
| t <sub>pLZ</sub> , t <sub>pZL</sub> | $ \begin{array}{cccccccccccccccccccccccccccccccccccc$ |  |  |  |
| t <sub>pHZ</sub> , t <sub>pZH</sub> | GND   |  |  |  |

Figure 1

### **AC Waveform**

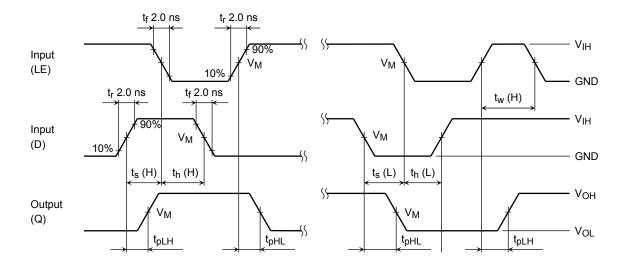


Figure 2  $t_{pLH}$ ,  $t_{pHL}$ ,  $t_w$ ,  $t_s$ ,  $t_h$ 

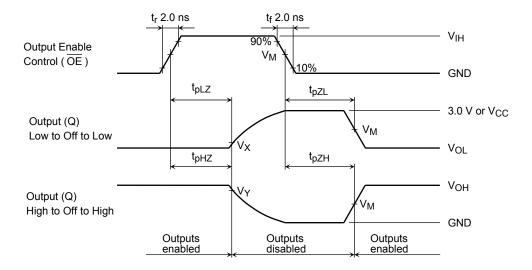


Figure 3  $t_{pLZ}$ ,  $t_{pHZ}$ ,  $t_{pZL}$ ,  $t_{pZH}$ 

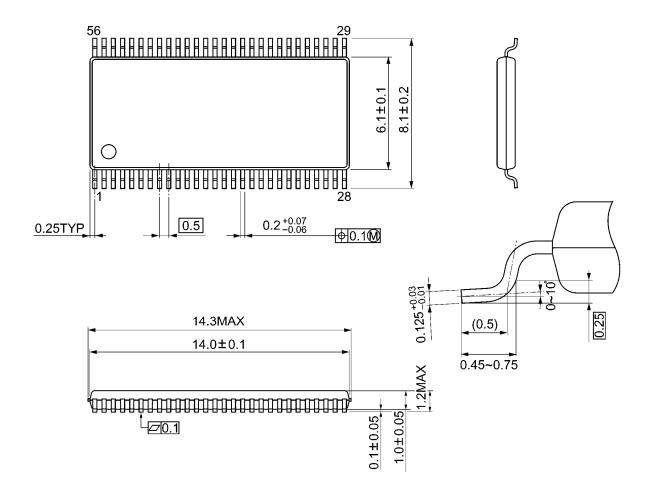
| Symbol          | V <sub>CC</sub>         |                          |                          |  |  |  |  |
|-----------------|-------------------------|--------------------------|--------------------------|--|--|--|--|
| Syllibol        | $3.3\pm0.3~\textrm{V}$  | $2.5\pm0.2\textrm{V}$    | 1.8 V                    |  |  |  |  |
| V <sub>IH</sub> | 2.7 V                   | V <sub>CC</sub>          | V <sub>CC</sub>          |  |  |  |  |
| V <sub>M</sub>  | 1.5 V                   | V <sub>CC</sub> /2       | V <sub>CC</sub> /2       |  |  |  |  |
| VX              | V <sub>OL</sub> + 0.3 V | V <sub>OL</sub> + 0.15 V | V <sub>OL</sub> + 0.15 V |  |  |  |  |
| VY              | V <sub>OH</sub> – 0.3 V | V <sub>OH</sub> – 0.15 V | V <sub>OH</sub> – 0.15 V |  |  |  |  |

10 2007-10-19

### **Package Dimensions**

**TOSHIBA** 

TSSOP56-P-0061-0.50A Unit: mm



Weight: 0.25 g (typ.)

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